

UTC UNISONIC TECHNOLOGIES CO., LTD

K4059 **Preliminary** N-CHANNEL JFET

FIELD EFFECT TRANSISTOR **SILICON N CHANNEL** JUNCTION TYPE

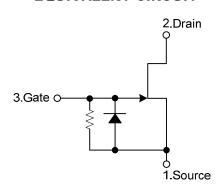
DESCRIPTION

The UTC K4059 is an N-channel JFET, it uses UTC's advanced technology to provide customers with low input capacitance and low forward transfer admittance.

FEATURES

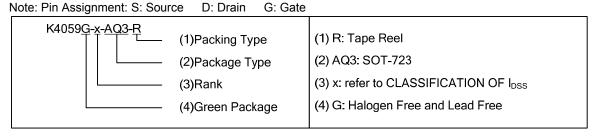
- * Low forward transfer admittance
- * Low input capacitance

EQUIVALENT CIRCUIT

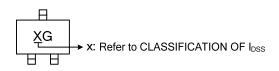


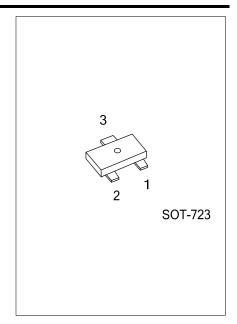
ORDERING INFORMATION

Ordering Number	Dookogo	Pin Assignment			Dooking	
Ordering Number	Package	1	2	3	Packing	
K4059G-x-AQ3-R	SOT-723	S	D	G	Tape Reel	



MARKING





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■ ABSOLUTE MAXIMUM RATINGS (T_A=25°C ,unless otherwise specified)

PARAMETER	SYMBOL	RATINGS	UNIT
Gate-Drain Voltage	V_{GDO}	-20	V
Gate-Current	I_G	10	mA
Drain Power Dissipation (T _A =25°C)	P_{D}	100	mW
Junction Temperature	TJ	125	°C
Storage Temperature Range	T _{STG}	-55~125	°C

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

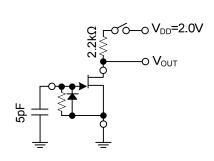
■ ELECTRICAL CHARACTERISTICS (T_A=25°C ,unless otherwise specified)

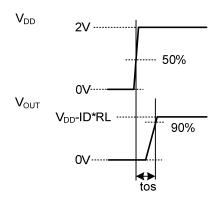
PARAMETER	SYMBOL	TEST CONDITIONS		MIN	TYP	MAX	UNIT
	I _{DSS}		K4059-A	140		240	μA
Drain Current		V_{GS} =0, V_{DS} =2 V	K4059-B	210		350	μΑ
			K4059-C	320		500	μΑ
Drain Current	I _D	V_{DD} =2V, R_L =2.2k Ω , C_g =5pF	K4059-A	125		260	μΑ
			K4059-B	190		370	μΑ
			K4059-C	290		500	μΑ
Gate-Drain Voltage	$V_{(BR)GDO}$	I _G =-10μA		-20			V
Gate-Source Cut-Off Voltage	V _{GS (OFF)}	$V_{DS}=2V$, $I_D=1\mu A$		-0.1		-1.0	V
Forward Transfer Admittance	Y _{fs}	V _{DS} =2V, V _{GS} =0V		1.35	1.85		mS
Input Capacitance	C _{ISS}	V _{DS} =2V, V _{GS} =0, f=1MHz			4.0		pF
		$V_{DD}=2V,R_L=2.2k\Omega$	K4059-A	-1.2	+0.9		dB
Voltage Gain	G∨	C _g =5pF, f=1kHz,	K4059-B	-0.2	+1.4		dB
		V _{IN} =100mV	K4059-C	+0.5	+1.8		dB
Delta Voltage Gain	$\Delta G_{V(f)}$	V_{DD} =2V, R _L =2.2k Ω , C _g =5pF, f=1kHz~100Hz, V _{IN} =100mV			0	-1	dB
	$\Delta G_{V(V)}$	$V_{DD}=2V\sim1.5V,R_L=2.2k\Omega$	K4059-A		-0.6	-1.1	dB
Delta Voltage Gain		C _g =5pF, f=1kHz,	K4059-B		-0.8	-1.7	dB
		V _{IN} =100mV	K4059-C		-1.4	-3.2	dB
		V_{DD} =2V, R_L =1k Ω ,	K4059-A		33	75	mV
Noise Voltage		C_g =10pF, G_V =80dB,	K4059-B		38	80	mV
		A-Curve Filter	K4059-C		42	90	mV
		V_{DD} =2V, R_L =2.2k Ω ,	K4059-A		1.3		%
Total Harmonic Distortion	THD	C _g =5pF, f=1kHz,	K4059-B		0.6		%
		V _{IN} =50mV	K4059-C		0.1		%
Time Output Stability	tos	V_{DD} =2V, R_L =2.2k Ω , C_g =5p	F		100	200	ms

■ CLASSIFICATION OF I_{DSS}

	RANK	А	В	С		
Ī	RANGE	140-240	210-350	320-500		

■ TEST CIRCUIT





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